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CAU 2811

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Docket: 0756-1998

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of)	80
Shunpei YAMAZAKI et al.)	Group Art Unit: 2841 🗠 🔟
Serial No. 09/352,194)	A V
Filed: July 13, 1999)	Examiner: F. ABRAHA
For: CRYSTALLINE SEMICONDUCTOR)	%O(
THIN FILM, METHOD OF FABRICATING)	3
THE SAME, SEMICONDUCTOR)	
DEVICE, AND METHOD OF FABRICATING)	CERTIFICATE OF MAILING
THE SAME)	

)

Commissioner for Patents Washington, D.C. 20231

Sir:

I hereby certify that this correspondence is being deposited with the United States Postal Service with sufficient postage as First Class Mail in

sufficient postage as First Class Mail in an envelope addressed to: Assistant Commissioner for Patents, Washington D.C. 20231 on 81000

Transmitted herewith is an Amendment and Response to Restriction Requirement in the above-identified application.

The fee has been calculated as shown below:

	Claims Remaining After Amendment		Highest Number Previously Paid For	Present Extra	Small/Large Entity Rate	Fee
Total	23	Minus	20	3	x \$9/\$18	\$ 54.00
Indep.	8	Minus	8	-0-	x \$39/\$78	\$0.00
First Presentation of Multiple Dependent Claim + \$130/\$260						\$0.00
TOTAL						\$54.00

- [X] A check in the amount of \$54.00 to cover the additional claims is enclosed.
- [X] In the event applicant(s) has overlooked the need for any petition and fee for extension of time, and such extension is required, applicant(s) requests that this be considered a petition therefor and that such fee be charged to Deposit Account No. 19-2380.

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[X] The Commissioner is hereby authorized to charge fees under 37 CFR 1.16, 1.17 (except the Issue Fee) which may be required now or hereafter, or credit any overpayment, to Deposit Account No. 19-2380. A duplicate copy of this sheet is attached.

Respectfully submitted,

Jeffrey L. Costellia

NIXON PEABODY LLP 8180 Greensboro Drive, Suite 800 McLean, Virginia 22102 (703) 790-9110

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In re Patent Application of Shunpei YAMAZAKI et al. Serial No. 09/352,194 Filed: July 13, 1999 For: CRYSTALLINE SEMICONDUCTOR THIN FILM, METHOD OF FABRICATING THE SAME, SEMICONDUCTOR DEVICE, AND METHOD OF FABRICATING) THE SAME

Group Art Unit: 2811

Examiner: F. ABRAHAM

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AMENDMENT AND RESPONSE TO RESTRICTION REQUIREMENT

Assistant Commissioner for Patents Washington, D.C. 20231

Sir:

In response to the Office Action of July 10, 2000, please amend the subject application as follows:

IN THE SPECIFICATION:

Page 30, line 16, change "15" to --VA--.

IN THE CLAIMS:

Cancel claims 1-4 without prejudice to applicants' to file a divisional application with respect thereto.

Please add the following new claims:

--19. A method of fabricating a semiconductor device including a thin film transistor, wherein the thin film transistor is formed through the steps of: